

Prabodh Shukla*

Physics Department

North Eastern Hill University

Shillong-793 022, India.

We analyze the energetics of domains and interfaces in the presence of quenched random fields, particularly at the lower critical dimension of the random field Ising model. The relevance of this study to experiments is also discussed.

I. INTRODUCTION

Uniformly ordered ferromagnetic states tend to break up into domains due to a variety of reasons. The most familiar reason is the competition between short-range exchange forces, and long-range dipolar forces. The domain structure has a lower free energy than the uniformly ordered ferromagnetic state. Imry and Ma [1] argued that quenched random fields in a system may also cause a uniform ferromagnetic state to break into domains. The main result of Imry and Ma is that there is a lower critical dimensionality for a system below which an arbitrarily weak, quenched random field with average value zero would destroy the uniform ferromagnetic order even at zero temperature. They concluded that the lower critical dimensionality is equal to two for spins of discrete symmetry (Ising spins), and four for spins of continuous symmetry (XY or Heisenberg spins). The argument of Imry and Ma is intuitively appealing, but nonrigorous. It remained unclear for several years if the results obtained from the argument were correct. The controversy was generated by the existence of another argument based on a field theoretic method that predicted the lower critical dimensionality of a pure (i.e. not disordered) system to be two dimensions lower than the lower critical dimensionality of corresponding random field system. The lower critical dimensionality of pure Ising model is equal to one, and that of continuous spin model is equal to two. Thus the dimensional reduction argument predicted the lower critical dimensionality of random field Ising model to be three, and that of random field continuous spin model to be four. It took several years to realize the error in the dimensional reduction argument, and to resolve that the results obtained on the basis of the Imry-Ma argument are correct.

In section II, we define a classical spin model of ferromagnetism incorporating random fields, and recapitulate the arguments due to Imry and Ma for the existence of domains in the ground state of the model if the dimensionality of the system is lower than a critical dimension. Quenched random fields are actually realized in several experiments. In the following, we illustrate this with a few widely studied examples [2, 3]. We also mention briefly the difficulties involved in the experiments, and in the interpretation of experiments. It is due to these difficulties that the controversy between the domain wall theory and the dimensional reduction theory could not be resolved for several years based on experiments alone.

Although the domain argument gives the correct value of the lower critical dimension, it becomes inconclusive exactly at the lower critical dimension. It fails to clarify if Ising spins in two dimensions, and continuous spins in four dimensions can support true long range ferromagnetic order. In section III, we discuss in detail the random field Ising model in two dimensions focusing on the nature of domain walls and their roughness in this model. We conclude that there is no long range ferromag-

*Electronic address: shukla@nehu.ac.in

netic order in the two dimensional random field model. Our presentation is largely based on the work of Binder [4] supplemented with numerical simulation of the model. One might also wish to examine more closely continuous spin models in four dimensions because domain wall arguments are inconclusive here as well. However, we do not go into this analysis, and not much is published on this problem. The reason is perhaps historical. The conflict between the domain wall theory and the dimensional reduction theory occurred in the case of lower critical dimension of random Ising systems, and therefore the bulk of the study has been on the random field Ising model.

II. DOMAINS IN QUENCHED RANDOM FIELDS

We first describe the random field model for classical spins. A classical spin is an n -component unit vector; it is called an Ising spin if $n=1$, XY spin if $n=2$, and Heisenberg spin if $n=3$. Higher values of n may also be considered. The limit $n \rightarrow \infty$ is known as the spherical model. Mutually interacting spins of continuous symmetry ($n \geq 2$) do not have a gap between the ground state and low lying excited states, while the spins of discrete symmetry ($n=1$) do have a gap. Therefore the qualitative behavior of continuous spin models is different from that of the Ising model. For simplicity, we shall focus on the Ising model. The model is defined on a d -dimensional hypercubic lattice. Each site is labeled by an integer i , and carries a classical spin S_i that takes the value $+1$ if the spin is pointing along the positive z -axis, and -1 if it is pointing along the negative z -axis. Each site also carries a quenched random magnetic field h_i . The set of fields $\{h_i\}$ are independent identically distributed random variables with a continuous probability distribution $\phi(h_i)$. There is a ferromagnetic interaction J between nearest neighbor spins. The Hamiltonian of the system is

$$H = -J \sum_{i,j} S_i S_j - \sum_i h_i S_i \quad (1)$$

In the absence of the random field, the ground state of the system at zero temperature has all spins aligned parallel to each other. The ground state is doubly degenerate. The energy of the system when all spins are pointing up is the same as when they are all pointing down. To be specific, we choose the state with all spins pointing up i.e. $S_i = 1$ for each site i , and focus on a block of linear dimension L inside the infinite system. The volume of the block is L^d . The number of lattice sites and therefore the number of spins contained in the block is also of the order of L^d . The surface of the block is of the order of L^{d-1} . If the spins in the entire block were to flip down simultaneously, the bulk energy of the block would not be affected because the spins are still aligned parallel to each other. However, the block would now appear as a defect in the background of up spins. The energy of this defect will be the surface energy of the block. The surface energy is of the order of JL^{d-1} . In the absence of thermal energy or random fields, there is no possibility that the block will flip down spontaneously in the fashion envisaged above. Now consider the effect of random fields. The energy of spin S_i in the field h_i is equal to $h_i S_i$ or simply h_i since $S_i = 1$. Thus the random field energy of the block is simply the sum of L^d random fields inside the block. This sum is equally likely to be positive or negative, and is of the order of $\sigma L^{d/2}$, where σ is the root mean square deviation of the random fields from their average value zero. The surface energy of the block is always positive. If the random field energy is negative and overwhelms the surface energy, the block will flip down spontaneously to lower its energy. Imry and Ma argue that if $d/2 > (d-1)$, i.e. if $d < 2$, then for any σ , there will be a characteristic length L^* such that the bulk energy gain will dominate over the surface energy loss for $L > L^*$. In other words, domains will occur spontaneously if $d < 2$. The characteristic length L^* is given by the equation,

$$\sigma[L^*]^{d/2} = J[L^*]^{d-1}, \text{ or } L^* = \left[\frac{J}{\sigma} \right]^{\frac{2}{(2-d)}} \quad (2)$$

As may be expected, the characteristic size of the domain L^* decreases with increasing disorder σ . Although we have considered the formation of a single defect in a uniform ferromagnetic state, numerous domains of linear size L^* will be formed in the system if $d < 2$, and the uniform ferromagnetic state will be completely destroyed. The density of domains is inversely related to their characteristic area. On the basis of arguments presented above, Imry and Ma concluded that the lower critical dimensionality of the random field Ising model is two, i.e. the model would not support a uniform ferromagnetic state if the dimensionality of the system is lower than two. The argument is inconclusive in two dimensions.

Equation (1) is readily generalized to continuous spins. The Hamiltonian is given by,

$$H = -J \sum_{i,j} \vec{S}_i \cdot \vec{S}_j - \sum_i \vec{h}_i \cdot \vec{S}_i \quad (3)$$

The spin $\vec{S}_i$, and the field $\vec{h}_i$ are now n -component vectors. In the absence of the random field, the ground state of the system at zero temperature is infinitely degenerate. We choose one of the degenerate states, and consider the energetics of the formation of a reversed spin block of size L . The random field energy of the block is calculated as before, but the surface energy gets modified. In the case of discrete spins the surface of the block is sharp. It cuts a pair of spins that are oriented opposite to each other. Ising spins can only point up or down. They cannot "tilt". The energy of a pair of Ising spins across the wall is equal to J compared with $-J$ in the absence of the wall. Continuous spins can tilt and the system utilizes this flexibility to lower its free energy. The change from up orientation outside the block to down orientation inside the block is achieved gradually by bending away from the z -axis over a distance that is known as the width of the domain wall. The advantage of bending away from the z -axis is that each pair of nearest neighbor spins in a domain wall is nearly parallel, and therefore it is an energetically favorable way of creating a defect. Suppose the angle between a pair of nearest neighbor spins in a domain wall is equal to θ . The energy of the pair with reference to the ground state without any defect is therefore equal to $-2J(1 - \cos \theta)$, or $J\theta^2$ in the limit $\theta \rightarrow 0$. If the width of the domain wall is ω (i.e. there is a chain of ω bent spins between an up spin and a down spin), θ is equal to π/ω , and the energy cost of a wall of thickness ω is approximately equal to $\omega (\pi/\omega)^2$, or π^2/ω . This shows that the energy cost of a wall goes to zero as the thickness of the wall goes to infinity. In a real physical system, there is often an axis of easy magnetization. The domains are oriented up or down along the axis of easy magnetization. Bending of spins away from the easy axis costs what is known as the anisotropy energy. The anisotropy energy increases with the width of the wall, and therefore limits the width of the domain wall. In our simple model, we have not considered the anisotropy energy term. However, recognizing that domain walls have to be finite, we may make the plausible assumption that the domain walls are of similar size as the domains. In this case, the domain wall energy (per unit area of the wall) is approximately equal to $J\pi^2/L$. Noting that the area of the wall scales as L^{d-1} , we find that the domain wall energy scales as JL^{d-2} . This is the energy cost of creating the domain. The gain from random fields scales as $\sigma L^{d/2}$ as before. Comparing the two terms we find the lower critical dimensionality for continuous spins is equal to four. The characteristic length L_c^* of domains in the continuous spin model is given by the equation,

$$\sigma[L_c^*]^{d/2} = J[L_c^*]^{d-2}, \text{ or } L_c^* = \left[\frac{J}{\sigma} \right]^{\frac{2}{(4-d)}} \quad (4)$$

III. RELEVANCE TO EXPERIMENTS

A random field is not merely a theoretical artifact. Defects and imperfections in magnets have the effect of creating a quenched random field in the system. We illustrate this with a few examples [2, 3] that have played an important role in investigating the effects of random fields experimentally.

The connection with experiments was first made by a theoretical argument due to Fishman and Aharony [2] who showed that a weakly diluted anti-ferromagnet in a uniform external field acts like a ferromagnet in a random field. Consider a one dimensional Ising anti-ferromagnet. Each unit cell has two spins, say S_1 and S_2 that are oriented opposite to each other. The order parameter (staggered magnetization per unit cell) is $S_1 - S_2$, and the total magnetization is $S_1 + S_2$. The system is exposed to a uniform external magnetic field h that couples to the total magnetization. In a randomly diluted system, one of the spins in a cell may be missing. Then the external field would couple to the remaining spin instead of the sum. The remaining spin may be written as an even or odd linear combination of the total and staggered magnetization. We may write $S_1 = [(S_1 + S_2) + (S_1 - S_2)]/2$, and $S_2 = [(S_1 + S_2) - (S_1 - S_2)]/2$. This means that in cells where one spin is missing, the external field couples to total magnetization as well as the staggered magnetization. The sign of the coupling to the staggered magnetization (the order parameter) is positive if S_2 is missing, and negative if S_1 is missing. The sign of the coupling between the order parameter and its conjugate field is random because either spin can be absent with equal probability. We may conclude from this that the critical behavior of a randomly diluted anti-ferromagnet in one dimension will be similar to that of a ferromagnet in a random field. The argument is generalizable to higher dimensions. An anti-ferromagnet without dilution has two sub-lattices on which the spins are oriented opposite to each other. One of the sub-lattice is aligned with the applied field. In the presence of dilution, locally the sub-lattice with most spins tends to align with the applied field in competition with the global anti-ferromagnetic order in the absence of dilution. As in the one dimensional case, the applied field acts as an effective random field coupling to the order parameter (staggered magnetization).

The effective random field produced by the applied field is proportional to the applied field. The strength of the random field is therefore easily controlled. One can do scaling studies with varying strengths of disorder in a system by simply tuning the applied field rather than making fresh samples with different degrees of dilution. This simplifying feature has a far reaching significance in investigating a theoretical model (RFIM) experimentally, and the interaction between theory and experiment has helped the field develop considerably, and clarified many fine points of the model [5].

If there is an experimental system that fits a theoretical model well, one may think that the predictions of the model may be tested easily by experiments. For example, the domain argument predicts the lower critical dimensionality of RFIM to be two, and the dimensional reduction argument predicts it to be three, so we may determine the correct value by doing an appropriate experiment. However, the interpretation of experiments is often not straightforward. Concentration gradients in the diluted sample tend to round off a transition and affect the measurements of critical behavior drastically. Further, the majority of experiments are performed on samples prepared in the following two ways; (i) cooling it in zero magnetic field, and (ii) cooling it in a magnetic field, and turning the field off at the end. Experiments on samples prepared in the two ways give different results. Three dimensional field cooled samples show no long range order and were first thought to show that the

lower critical dimensionality of RFIM is three. But three dimensional samples cooled in zero field showed long range order. So the question of lower critical dimensionality could not be settled by experiments initially. It was only after several years of controversy that the experimental situation resolved itself in favor of the domain argument, i.e. no long range order in two dimensions, but long range order in three dimensions. The main point that was clarified by theoretical work is that the field cooled state is not an equilibrium state. It relaxes logarithmically slowly, and one should not expect to see an equilibrium ordered state in a field cooled sample over any reasonable experimental time scale.

Rb_2CoF_4 is a good two dimensional Ising anti-ferromagnet [6]. It consists of layers of magnetic ions with a single dominant intralayer exchange interaction, and an interlayer interaction which is smaller by several orders of magnitude. It is very anisotropic so that the spins can be well represented as Ising spins. The material can be magnetically diluted by introducing a small fraction of manganese ions in place of cobalt ions. Crystals of $Rb_2Co_xMn_{1-x}F_4$ are good examples of a two dimensional diluted anti-ferromagnet suitable for an experimental realization of the two dimensional random field Ising model. In three dimensions, the most studied dilute anti-ferromagnet is $Fe_xZn_{1-x}F_2$ crystal. In the pure ferrous fluoride FeF_2 crystal [7], the ferrous ions (Fe^{++}) are situated approximately on a body centered tetragonal lattice. Each ferrous ion is surrounded by a distorted octahedron of fluorine (F^-) ions. The predominant interactions are a large single-ion anisotropy, and an anti-ferromagnetic exchange between nearest neighbor ferrous ions. The magnetic moments of ferrous ions on the corners of the tetragonal cell are anti-parallel to the magnetic moments of Fe^{++} ions on the body centers. The large crystal field anisotropy persists as the magnetic spins are diluted with Zn . The diluted crystal remains an excellent Ising anti-ferromagnet for all ranges of magnetic concentration x . Furthermore crystals with excellent structural quality can be grown for all concentrations x with extremely small concentration variation $\delta x < 10^{-3}$. These attributes combine to make $Fe_xZn_{1-x}F_2$ the popular choice for experiments on diluted anti-ferromagnets, although experiments have been done on several other materials as well [3].

IV. ROUGHNESS OF INTERFACES

The discussion in section (2) was based on domains having flat interfaces with other domains. For example, we considered a cube of upturned spins in a uniform ferromagnetic background. The faces of the cube defined the interface in this case. We could have considered a sphere of upturned spins in which case the interface would have been a surface of constant curvature. In both cases, the arguments for the stability of domains presented earlier would hold good. The question arises if our conclusions would hold even in the presence of rough interfaces with fluctuating curvature. It is conceivable that the freedom of a wandering interface in a random background would make it energetically more favorable for the system to break up into domains. In other words, the roughness of the interface could raise the lower critical dimensionality of the system from the value given by the domain argument. In order to address this concern, several workers reformulated the problem in terms of the interface. In this approach we focus on a single interface in the system. It is convenient to use a continuum model of the interface. We visualize the interface as an elastic membrane. A flat interface is described by a vector $\vec{\rho}$ in the (d-1)-dimensional hyperplane transverse to the z -axis. Fluctuations in the interface are described by a displacement $z(\rho)$ away from the flat surface ($z = 0$). The displacement $z(\rho)$ is a scalar that can take positive or negative values. The random field is denoted by a function $h(\rho, z)$ with the property,

$$\langle h(\rho_1, z_1)h(\rho_2, z_2) \rangle = \delta(\rho_1 - \rho_2)\delta(z_1 - z_2), \quad (5)$$

where δ denotes Dirac's delta function.

The Hamiltonian of the interface is written as,

$$H = J \int d\vec{\rho} [1 + (\vec{\nabla}_\rho z)^2]^{1/2} - \int d\vec{\rho} \int dz' h(\rho, z') \text{sign}[z' - z(\rho)] \quad (6)$$

The first term is the total area of the interface multiplied by the exchange energy J ; it gives the energy penalty for creating the interface. The second term is the random field energy gained in roughening the interface on the assumption that the spins are up above the interface and down below it. The Hamiltonian can be simplified by adding to it a constant term equal to

$$\int d\vec{\rho} \int dz' h(\rho, z') \text{sign}(z')$$

One gets,

$$H = J \int d\vec{\rho} [1 + (\vec{\nabla}_\rho z)^2]^{1/2} + 2 \int d\vec{\rho} \int_0^{z(\rho)} dz' h(\rho, z') \quad (7)$$

On length scales larger than the bulk correlation length, the slope of the interface $|\nabla_\rho|$ should be small in comparison with unity if the domain argument is to be valid. In the following, we shall assume that $|\nabla_\rho|$ is small, and explore the condition for the validity of this assumption. We therefore linearize the fluctuations in the interface to first order in $|\nabla_\rho|$. We also omit an infinite constant that does not depend on the fluctuations in the interface. Thus we write

$$H = \int d\vec{\rho} \left[\frac{1}{2} J |\vec{\nabla}_\rho z|^2 + V(\rho, z(\rho)) \right] \\ \text{where, } V(\rho, z(\rho)) = 2 \int_0^{z(\rho)} dz' h(\rho, z') \quad (8)$$

Often the potential energy term $V(\rho, z(\rho))$ is regarded as an independent random variable with mean value zero and variance given by,

$$\langle V(\rho_1, z_1) V(\rho_2, z_2) \rangle = \delta(\rho_1 - \rho_2) R(z_1 - z_2), \quad (9)$$

Here $R(z_1 - z_2)$ is a sort range function of its argument [8, 9].

We characterize the roughness of the interface over a length $|\rho_1 - \rho_2|$ in the mean interface plane by a quantity $\omega(|\rho_1 - \rho_2|)$ that is defined as follows:

$$\omega^2(|\rho_1 - \rho_2|) = \langle [z(\rho_1) - z(\rho_2)]^2 \rangle \quad (10)$$

Over large length scales, the roughness $\omega(|\rho_1 - \rho_2|)$ is characterized by an exponent ζ defined as follows:

$$\omega(|\rho_1 - \rho_2|) = |\rho_1 - \rho_2|^\zeta \quad (11)$$

If the exponent ζ is nonzero, but less than unity, the interface is called a self-affine interface.

We shall not go into the detailed analysis of the interface Hamiltonian, but be content to give rough scaling arguments to show that the interface approach to the problem of lower critical dimensionality

yields the same result as the domain approach. We approximate $|\vec{\nabla}_\rho z(\rho)|$ by $\omega(L)/L$, i.e. the ratio of the height of the interface to its linear extension. In this rather crude approximation the energy of the interface scales as

$$\Delta E = JL^{d-1} \left[\frac{\omega}{L} \right]^2 - \sigma \sqrt{\omega L^{d-1}}$$

The first term gives the energy cost of creating a fluctuation in a flat interface and the second term the energy gain from the fluctuation (the sum of random fields under the interface). The two terms should balance each other in equilibrium. Differentiating ΔE with respect to the height of the interface ω , we get the scaling relations

$$\omega(L) = \left[\frac{\sigma}{4J} \right]^{2/3} L^{\frac{5-d}{3}}, \text{ and } |\vec{\nabla}_\rho z(\rho)| = \frac{\omega}{L} \sim L^{\frac{2-d}{3}}$$

The above relations predict that the interface roughness is negligible if $d > 2$. The domain theory presented in section (2) assumes that the interfaces are not rough. We have now shown that this assumption is justified if the dimensionality of the system is greater than two. Actually, the interface approach is not fundamentally different from the domain approach. Therefore the interface analysis presented above should be seen as a consistency check with the domain approach, rather than an independent proof of the results of the domain theory. The central result of both approaches is that the lower critical dimensionality of the random field Ising model is equal to two.

V. ABSENCE OF ORDER IN 2D RFIM

Consider an $L \times L$ square of down spins in a plane of up spins. Our task is to investigate if this defect or a similar defect can appear spontaneously in the two dimensional random field Ising model? The energy of the defect (referred to the uniform state with all spins up) is equal to

$$\Delta E = 8JL - 2\sigma L$$

The first term is the energy required to create a domain wall along the edges of the square. Each of the four edges of length L requires an energy $2JL$. The second term gives the possible gain in energy (with probability half) from the random fields inside the square. There are L^2 sites inside the square. The sum of random fields inside the square is therefore approximately equal to $\pm \sigma L$. The sum is equally likely to be positive or negative. Only if the sum is negative, the block gains energy by flipping down. However, if $\sigma < 4J$, the gain from random fields is not sufficient to compensate the loss from domain walls. Therefore at first thought it appears that the long range ferromagnetic order will remain stable in the presence of small disorder ($\sigma < 4J$).

We show in the following that sufficient energy may be gained from random fields to compensate the loss due to domain walls if roughening of the domain walls is taken into account. Suppose the square of down spins is placed in the first quadrant of the xy plane such that the bottom left corner of the square coincides with the origin of the coordinate system. For simplicity, we focus on the roughening of just one edge of the square, say the bottom edge along the x -axis from $x=0$ to $x=L$. Spins above the edge are down, and those below it are up.

Following Binder [4], we cut the wall into smaller pieces along its length and allow each piece to move up or down without bending. The cuts along the length are made in an iterative, self-similar manner on smaller and smaller length scales. First the entire wall is allowed to move up or down till it gains maximum energy from the random fields. Then, the wall in its new position is cut into n segments of equal length. Each segment is allowed to move up or down in order to lower the

energy of the system. The process is repeated by cutting each segment into n equal pieces again, and relaxing each piece without allowing it to bend.

Suppose the entire length L of the horizontal wall moves vertically by a distance ω when relaxed. The area covered by the moving wall is equal to ωL , and therefore the gain from random fields is equal to $-\sigma\sqrt{\omega L}$. The wall may move up or down with equal probability. We consider the case when the wall moves down. In this case the patch of down spins increases in area from an $L \times L$ square to a rectangle $L \times (L + \omega)$ rectangle, and an extra vertical wall of length ω has to be created on each side of the moving wall. This costs an energy equal to $2J\omega$ on each side. The total energy change in relaxing the wall is equal to,

$$\Delta E = 4J\omega - \sigma\sqrt{\omega L} \quad (12)$$

Minimizing the above expression with respect to ω gives

$$\omega = \left(\frac{\sigma}{8J}\right)^2 L \quad (13)$$

Substituting from equation (13) into equation (12) gives,

$$\Delta E = -4J\left(\frac{\sigma}{8J}\right)^2 L \quad (14)$$

Next we divide the wall into n equal segments. Each segment of length L/n is relaxed independently. It moves a distance ω_1 , and gains an energy for the system equal to ΔE_1 given by,

$$\omega_1 = \left(\frac{\sigma}{8J}\right)^2 \frac{L}{n}; \quad \Delta E_1 = -4J\left(\frac{\sigma}{8J}\right)^2 \frac{L}{n} \quad (15)$$

Dividing each segment of length L/n into further n equal segments, and relaxing each smaller segment independently yields,

$$\omega_2 = \left(\frac{\sigma}{8J}\right)^2 \frac{L}{n^2}; \quad \Delta E_2 = -4J\left(\frac{\sigma}{8J}\right)^2 \frac{L}{n^2} \quad (16)$$

The process is continued till the typical distance moved by the smallest segment is of the order of unity. Note that distances less than unity (in units of lattice constant) do not have any physical significance on a lattice. Suppose it takes k_{max} iterations to reach the end, i.e.

$$\omega_{k_{max}} = \left(\frac{\sigma}{8J}\right)^2 \frac{L}{n^{k_{max}}} = 1, \quad (17)$$

or,

$$k_{max} = \left\lceil \frac{2 \log \left(\frac{\sigma}{8J}\right) + \log L}{\log n} \right\rceil \quad (18)$$

The energy gained in the entire process of relaxation is given by,

$$\Delta E = \sum_{k=0}^{k=km\alpha x} n^k \Delta E_k = -4J \left(\frac{\sigma}{8J} \right)^2 L \times (km\alpha x + 1) \quad (19)$$

Or,

$$\Delta E = -4J \left(\frac{\sigma}{8J} \right)^2 L \times \left[\frac{2 \log \left(\frac{\sigma}{8J} \right) + \log L + \log n}{\log n} \right] \quad (20)$$

In the limit $\sigma \rightarrow 0$, and $L \rightarrow \infty$, the dominant term becomes

$$\Delta E = -4J \left(\frac{\sigma}{8J} \right)^2 \left[\frac{L \times \log L}{\log n} \right] \quad (21)$$

Thus the energy gained from random fields by roughening the domain scales as $L \log L$. Roughening of the flat domain wall also increases its length. However, the increase in the length of the domain wall due to roughening is marginal in cases where the domain wall is well defined. In order to see this, we estimate the new length of the staggered contour describing the interface:

$$L_{new} = L + \sum_{k=0}^{k=km\alpha x} n^k |\omega_k| = L \left[1 + \left(\frac{\sigma}{8J} \right)^2 (km\alpha x + 1) \right] \quad (22)$$

$$= L \left[1 + \left(\frac{\sigma}{8J} \right)^2 \cdot \left\{ \frac{2 \log \left(\frac{\sigma}{8J} \right) + \log L + \log n}{\log n} \right\} \right] \quad (23)$$

The first term is the leading term in the limit $L \rightarrow \infty$, $\sigma \rightarrow 0$. The maximum excursion of the rough interface away from its initial flat position is estimated as,

$$\omega_{max} = \sum_{k=0}^{k=km\alpha x} |\omega_k| = \left(\frac{\sigma}{8J} \right)^2 L \sum_{k=0}^{k=km\alpha x} n^{-k} \approx \left(\frac{\sigma}{8J} \right)^2 L \quad (24)$$

The average square deviation from the flat interface is given by,

$$\langle \omega^2(L) \rangle = \sum_{k=0}^{k=km\alpha x} \omega_k^2 = \left(\frac{\sigma}{8J} \right)^4 L^2 \sum_{k=0}^{k=km\alpha x} n^{-2k} \approx \left(\frac{\sigma}{8J} \right)^4 L^2 \quad (25)$$

The characteristic length scale L^* over which the energy gained by the rough interface becomes comparable to the cost of making the interface is given by the equation,

$$\Delta E \approx 2JL - 4J \left(\frac{\sigma}{8J} \right)^2 \left[\frac{L \times \log L}{\log n} \right] \approx 0$$

The coefficients of the two terms in the middle are not intended to be exact. The important point is that the first term (the cost of making a domain wall) is linear in L , and the second term (the gain from roughening the wall in random fields) is of the order of $L \log L$. The characteristic

length L^* is the minimum length beyond which ΔE can become negative, and therefore the system can spontaneously break up into domains. Approximately,

$$L^* \approx \left(\frac{\sigma}{J}\right)^2 L^* \times \log L^*; \text{ or } \log L^* \approx \left(\frac{J}{\sigma}\right)^2; \text{ or } L^* \approx \exp\left(\frac{J}{\sigma}\right)^2$$

It is easily checked that over length scales L^* , the total length of the staggered contour of the interface is of the order L^* because $(\sigma/J)^2 \log L^*$ is of the order unity. This proves an assumption made earlier that there is a length scale over which the cost of the domain wall scales as L , and the gain from random fields as $L \log L$. The gain from random fields dominates over the cost of making a domain wall for $L > L^*$, and the system forms domains spontaneously. Hence we conclude that the two dimensional random field Ising model does not support long range ferromagnetic order in the limit of infinite system size.

A few remarks are in order:

1. The energy gained from random fields depends on a parameter n that is an artifact of our method of estimation of the energy. However this dependence is rather weak because it arises via a $\log n$ factor. It is not expected to seriously affect the conclusions drawn above.
2. Excursion of the wall at the k -th step may take it into a region already crossed by the wall at the previous step. Thus ΔE_k may have a contribution that is already included in ΔE_{k-1} . In other words, there may be a problem of double counting in our procedure. Binder [4] argues that this problem is not serious.
3. Binder [4] also argues that the conclusions drawn above would hold even if all cuts of the flat interface at the k -th stage are not exactly equal to L/n^k , but are equal to this value on the average.

VI. A TOY PROBLEM

The analysis presented in the preceding section shows that the energy gained by an interface from roughening in a random background scales as $L \log L$, where L is the length of the interface. This result is extracted after several simplifying assumptions and approximations. It is therefore desirable to check the theoretical prediction against numerical simulations of the model. The difficulty is that the numerical simulation of the minimum energy configuration of an interface in a random background is almost as difficult as an exact theoretical solution of the problem. We therefore adopt an algorithm that has the virtue of being efficient, and we hope that it captures the essence of the physical problem. Simulation of our toy problem on systems of moderate size appear to bear out the theoretical predictions of the previous section [10].

We consider a square lattice of size $L \times L$, and an interface that joins the bottom left corner of the square to the top right corner. It is convenient to consider the bottom left corner as the origin of the coordinate system; the bottom edge of the square as the x -axis; and the left edge as the y -axis. The interface is modeled by the path of a directed walk along the nearest neighbor bonds on the lattice. The walk is always directed along the positive y -axis and the positive x -axis. The interface made by such a walk does not have any overhangs or loops. For simplicity, we assume that the spins above the interface are down, and those below it are up. The spins reside in the middle of plaquettes made by joining nearest neighbor bonds around square unit cells. The spins are conveniently labeled by cartesian coordinates (i, j) where i denotes the i -th row from below, and j -th column from left. A spin in the plaquette (i, j) experiences a random field $h(i, j)$.

Our object is to find an interface that divides the up spins from the down spins in such a way that the net interaction energy of the spins with the random fields at their sites is minimum. We consider the spins in one column of the square at a time. Suppose the interface in the first column separates i spins below the interface that are up, from $L - i$ spins above the interface that are down ($0 \leq i \leq L$). The magnetic energy of the first column can be written as,

$$E(i, 1) = \sum_{i'=0}^{i'=L} h(i', 1) S_{i', 1} = \sum_{i'=0}^{i'=i} h(i', 1) - \sum_{i'=i+1}^{i'=L} h(i', 1) \quad (26)$$

A computer algorithm generates random fields $h(i, 1)$; and computes $E(i, 1)$ for each row in the first column ($i = 1, 2, \dots, L; j = 1$). The same process is repeated for the second column, i.e. we generate random fields $h(i, 2)$, and compute $E(i, 2)$ for each row in the second column. Now a naive approach may be to put the interface at a position in the first column that corresponds to the minimum energy in the set $\{E(i, 1)\}$, and put the interface in the second column that corresponds to the minimum energy in the set $\{E(i, 2)\}$ subject to the restriction that the interface in the second column be placed at the same level or above the interface in the first column. Our algorithm described below is an improvement over this naive approach. We compute a quantity $E_{min}(i, 2)$ for each row in the second column from $E(i, 2)$ and $\{E(i, 1)\}$ as follows:

$$E_{min}(i, 2) = \text{Min}(0 \leq j \leq i) [E(i, 2) + E(j, 1)] \quad (27)$$

This process is recursed to calculate $E_{min}(i, 3)$ from $E(i, 3)$ and $\{E_{min}(i, 2)\}$; and so on.

$$E_{min}(i, 3) = \text{Min}(0 \leq j \leq i) [E(i, 3) + E_{min}(j, 2)] \quad (28)$$

After L recursions of the process we get,

$$E_{min}(i, L) = \text{Min}(0 \leq j \leq i) [E(i, L) + E_{min}(j, L - 1)] \quad (29)$$

The quantity $E_{min}(L, L)$ gives the minimum energy required to place an interface diagonally across the square. Equivalently, $E_{min}(L, L)$ is the maximum energy that an interface whose length is of the order of L can gain by roughening itself in the background of quenched random fields.

Figure 1 shows the results of numerical simulations on systems of linear size varying from $L = 5$ to $L = 100$. $E_{min}(L, L)/L$ is plotted along the y-axis against $\log L$ on the x-axis. The figure shows graphs for three distinct distributions of the random field: (i) random fields taking two discrete values ± 1 with equal probability, (ii) a continuous rectangular distribution of width 2 centered around the origin, and (iii) a gaussian distribution of variance unity. The data has been averaged over 10^6 independent realizations of the random field distribution. The figure suggests that the energy gained by the interface from random fields scales as $L \log L$. The data for the rectangular distribution has been multiplied by $\sqrt{3}$. The modified data for the rectangular distribution (after multiplication by $\sqrt{3}$) lies very close to the data for the discrete ± 1 distribution. This may be expected because the standard square deviations of the two distributions are in the ratio $1 : \frac{1}{3}$.

VII. THERMAL EFFECTS

At finite temperatures, interfaces are roughened by thermal energy as well as by quenched disorder. Let ξ_d be the length scale that describes roughening due to disorder at zero temperature, and ξ_T be

the characteristic length over which the interface would roughen due to temperature if there were no disorder. As discussed in the previous section, ξ_d is the smallest portion of a straight line interface that moves sideways by a unit distance when the interface is relaxed in a random background. We get from equation (17),

$$\xi_d = \left(\frac{8J}{\sigma} \right)^2 \quad (30)$$

The thermal length ξ_T is the typical distance one has to move along a straight interface before one finds a kink (i.e. a sideways turn of the interface) due to thermal fluctuation. The density of kinks is proportional to the Boltzmann factor $\exp(-2J/k_B T)$. Therefore,

$$\xi_T = \exp \left(\frac{2J}{k_B T} \right) \quad (31)$$

Let us consider a system with fixed disorder σ , and raise its temperature gradually above zero. At very low temperatures we have $\xi_T \gg \xi_d$ and therefore roughening of the interface is dominated by disorder. As may be expected, thermal fluctuations are essentially irrelevant at very low temperatures. At higher temperatures, when $\xi_T < \xi_d$, the thermal effects become relatively important and enhance roughening of the interface. Consider roughening by disorder at length scale L_k . The straight segment of length L_k will develop on average L_k/ξ_T kinks due to thermal fluctuations. Thus the mean square deviation $\langle \omega^2 \rangle_T$ due to thermal effects will be equal to

$$\langle \omega^2 \rangle_T = \frac{L_k}{\xi_T} = L_k \exp \left(- \frac{2J}{k_B T} \right) \quad (32)$$

The probability distribution of the interface width may be written as

$$P_T(\omega) \approx \exp \left[- \frac{\omega^2}{2 \langle \omega^2 \rangle_T} + \frac{\sigma \sqrt{\omega L_k}}{k_B T} \right] \quad (33)$$

The first term on the right is the distribution corresponding to a completely random (Gaussian) walk. The second term takes into account the energy that can be gained by excursions in a random field background. Minimizing $P_T(\omega)$ with respect to ω gives

$$\omega_l = \left(\frac{\sigma}{T} \right)^{\frac{2}{3}} L_k \exp \left(- \frac{4J}{k_B T} \right) \quad (34)$$

The energy gained from random fields at length scale L_k is given by

$$U_k = -\sigma \sqrt{\omega L_k} = -\sigma \left(\frac{\sigma}{T} \right)^{\frac{1}{3}} L_k \exp \left(- \frac{2J}{3k_B T} \right) \quad (35)$$

Summing over contributions from all independent length scales, we get the total gain in energy U from roughening of a domain wall in a random medium at a finite temperature

$$U = -\sigma \sqrt{\omega L_k} = -\sigma \left(\frac{\sigma}{T} \right)^{\frac{1}{3}} L \log L \exp \left(- \frac{2J}{3k_B T} \right) \quad (36)$$

The leading term in the cost of making a domain wall still scales linearly with the length of the wall. At a characteristic length L^* the energy cost and energy gain terms balance each other. We get

$$L^* = \exp \left[\left(\frac{J}{\sigma} \right) \left(\frac{T}{\sigma} \right)^{\frac{1}{3}} \exp \left(\frac{2J}{3k_B T} \right) \right] \quad (37)$$

As noted earlier in this section, the above equation applies in the regime $\exp(J/k_B T) < (8J/\sigma)$. Random field systems with linear size greater than L^* will spontaneously breakup into domains at temperature T . Our discussion assumes that we have an interface with no overhangs and bubbles. This assumption is justified if the density of kinks is negligible, or equivalently if $\xi_T \gg 1$. If overhangs and bubbles are present in the system, it is not possible to formulate the problem in terms of a single-valued variable $z(\rho)$ describing the transverse fluctuations of a wall from a (d-1)-dimensional flat reference plane.

At higher temperatures, at around the critical temperature of the pure (i.e. without disorder) system overhangs and bubbles are no longer negligible. At these temperatures, a new length ξ_c comes into play that describes the diverging correlation length of the pure system at its critical point. We have,

$$\xi(t) = t^{-\nu}, t = \frac{T_c - T}{T_c}, \quad (38)$$

where T_c is the critical temperature of the pure system, t is the reduced temperature, and ν is a critical exponent. In a domain of linear size ξ_c , the net random field is of the order of $\sigma \xi^{d/2}$, but the spins within the domain are not aligned parallel to each other to the same degree as at low temperatures. The average magnetization per spin is of the order of t^β , where β is another critical exponent. Thus the gain from random field energy is reduced to a quantity of the order of

$$U = \sigma \xi^{d/2} t^\beta = \sigma \xi^{\frac{d\nu - 2\beta}{2\nu}} = \sigma \xi^{\frac{\gamma}{2\nu}} \quad (39)$$

Here γ is the critical exponent describing the diverging susceptibility at the critical temperature. We have made use of the well known relations, $\alpha + 2\beta + \gamma = 2$, and $d\nu = 2 - \alpha$, where α is the critical exponent describing the singular part of the specific heat. Just as the thermal fluctuations reduce the gain from random fields by a factor t^β , they also reduce rather drastically the cost of making a domain wall. The domain walls become ill-defined and spread out over a distance comparable to the linear size of the domain, and therefore the cost of making a wall is reduced from $J\xi$ to J only. The cost and gain become comparable to each other at a value of ξ given by

$$\xi = \left(\frac{J}{\sigma} \right)^{\frac{2\nu}{\gamma}} \quad (40)$$

The crossover to the length scale ξ takes place at a temperature given by the reduced temperature

$$t = \left(\frac{\sigma}{J} \right)^{\frac{2}{\gamma}} \quad (41)$$

In summary, as the temperature of the system is increased keeping the amount of random disorder σ fixed, we may see crossover phenomena between different length scales; a crossover from ξ_d to

L^* , another from L^* to ξ , and finally from ξ to a distance of the order of unity at very high temperatures. It is plausible that the length scales are rather asymmetrical on the two sides of the transition temperature T_c of the pure system, and they remain finite and smaller than L^* in the vicinity of T_c due to slow relaxation of the system on experimental time scales. This speculation may possibly explain several observed phenomena in systems where the underlying lattice goes through a transition driven by a competition between temperature and quenched disorder.

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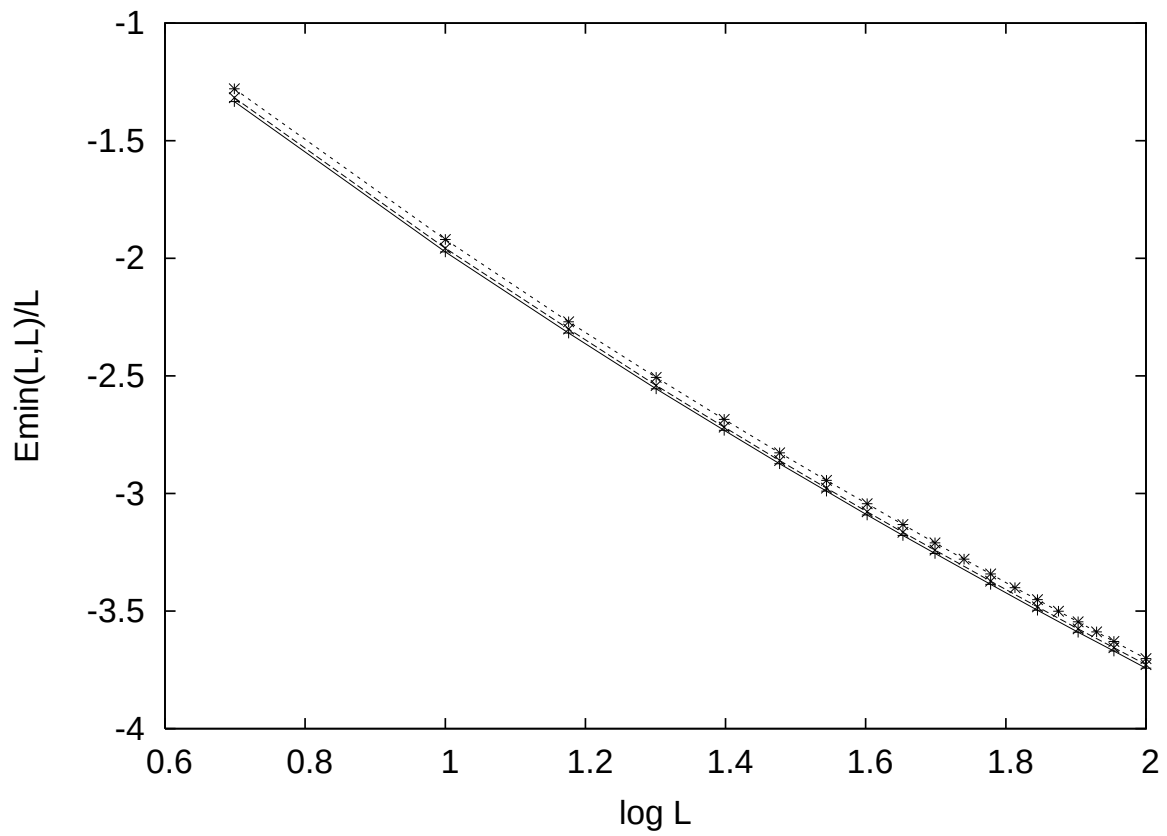


FIG. 1: Energy gained by roughening of a diagonal interface in an $L \times L$ square. The energy gain divided by L is plotted along the y-axis against $\log L$ on the x-axis. Simulations for three different random field distributions are shown. The lower curve is for a discrete distribution $h_i = \pm J$; the middle curve for a rectangular distribution of width $2J$ centered around the origin; the upper graph is for a Gaussian distribution of variance J . We have set $J = 1$, and scaled the middle curve by a factor $\sqrt{3}$ (see text). The figure suggests that the energy gain scales as $L \log L$.